PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE Reissue Patent Application:

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Applicant

Loi Nguyen and Ravishankar Sundaresan

Assignee

: STMicroelectronics, Inc.

Filed

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Title

SRAM CELL FABRICATION WITH INTERLEVEL

DIELECTRIC PLANARIZATION

Docket No.

1678-20

Corresponding Issued U.S. Patent:

Patent No.

5,710,461

Issued

January 20, 1998

Appln. No.

08/781,429

Filed

January 10, 1997

Examiner

A. Williams

Art Unit

2508

BOX PATENT APPLICATIONS Assistant Commissioner for Patents Washington, DC 20231

OFFER TO SURRENDER THE ORIGINAL PATENT

Sir:

STMicroelectronics, Inc., owner by assignment of the entire interest in U.S. Letters Patent No. 5,710,461 which is entitled SRAM CELL FABRICATION WITH INTERLEVEL DIELECTRIC PLANARIZATION and issued on January 20, 1998 to STMicroelectronics, Inc., hereby offers to surrender said Letters Patent.

STMicroelectronics, Inc.

	By:
Date	Archie McK. Malone
	Executive Vice President
	Finance & C F O and Treasurer

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Original Patent

Patentee: L

Loi Nguyen

Ravishankar Sundaresan

Patent No.:

5,710,461

Title:

SRAM CELL FABRICATION

WITH INTERLEVEL

DIELECTRIC PLANARIZATION

Issued:

January 20, 1998

Docket No.:

93-C-078C1

Reissue Application

Applicants:

Loi Nguyen

Ravishankar Sundaresan

Application No.:

Title: SRAM CELL FABRICATION WITH

INTERLEVEL DIELECTRIC

PLANARIZATION

Filing Date:

January 20, 2000

Docket No.:

93-C-078C1-RE (1678-20)

REISSUE APPLICATION DECLARATION BY THE INVENTORS

As below-named inventors, we hereby declare that:

Our residence, post office address and citizenship are as stated below.

We believe that we are the original, first and joint inventors of the innovative subject matter described and claimed in the application for reissue of U.S. Patent No. 5,710,461 ('461 patent), which is entitled "SRAM CELL FABRICATION WITH INTERLEVEL DIELECTRIC PLANARIZATION," the specification of which is attached hereto.

We hereby state that we have reviewed and understand the contents of the aboveidentified U.S. reissue patent application, including both the original claims and the new claims presented in the enclosed First Preliminary Amendment.

We acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulation, § 1.56(a).

We believe the above-identified original '461 patent to be partly inoperative, by reason of the patentees claiming less than we had a right to claim. This error arose without any deceptive intention on our part.

Accordingly, the enclosed First Preliminary Amendment presents amended independent claims and additional dependent claims. These claims have been amended and drafted to more particularly point out and distinctly claim various aspects of our invention. We believe that our invention is at least as broad as these claims.

At least one error upon which reissue is based is described as follows. Issued claims 1 and 7 recite "a third patterned thin-film layer comprising substantially undoped polysilicon having a very high resistivity," and issued claim 12 recites "an additional patterned thin-film layer comprising substantially intrinsic polysilicon." Each of these thin film layers corresponds to layer in which resistors for a static random access memory (SRAM) cell are formed. Regarding these resistors, the specification expressly states in column 4, lines 46-51, that "[a]lthough the resistors are formed from intrinsic polysilicon in the presently preferred embodiment, it will be recognized that a slight amount of doping may be desirable to stabilize the characteristics of this material. For example, this material may be doped with chlorine, or may be SIPOS (containing a large fraction of oxygen)." Thus, the "substantially undoped" language unduly limits the scope of isued claims 1 and 7, and the same is true of the "substantially intrinsic" language in original claim 12.

As named inventors, we hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: LISA K. JORGENSON, Reg. No. 34,845; THEODORE E. GALANTHAY, Reg. No. 24,122; ROBERT D. MCCUTCHEON, Reg. No. 38,717; JEFF MOY, Reg. No. 39,307; and the attorneys associated with customer no. 000996 as follows: BRYAN A. SANTARELLI, Reg. No. 37,560; JEFFREY T. HALEY, Reg. No. 34,834; STEPHEN M. EVANS, Reg. No. 37,128; RICHARD O. GRAY, Reg. No. 26,550; PAUL F. RUSYN, Reg. No. 42,118; and, JOSHUA KING, Reg. No. 35,570.

Correspondence Address: Direct all communications about the application to:

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Phone: (972) 466-6000

Fax: (972) 466-7044

We do not know and do not believe that the claimed invention was ever known or used in the United States of America before our invention thereof.

We do not know and do not believe that the claimed invention was ever patented or described in any printed publication in any country before our invention thereof.

We do not know and do not believe that the claimed invention was ever patented or described in any printed publication in any country more than one year prior to the filing date of the original U.S. application.

We do not know and do not believe that the claimed invention was ever patented or made the subject of an inventor's certificate issued prior to the date of this application in any country foreign to the United States of America on an application filed by us or our legal representatives or assigns.

We do not know and do not believe that the claimed invention was ever in public use or on sale in the United States of America more than one year prior to the filing date of the original U.S. application.

We hereby declare that all statements made of our knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and may also jeopardize the validity of the application or any patent issued thereon.

T 'NT	
Inventor: Loi Nguyen	Date
•	Date

Residence and Mailing Address: 1724 Brighton Drive, Carrollton, Denton, TX 75007

Citizenship: United States

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Inventor: Ravishankar Sundaresan	Date	
Residence and Mailing Address:		
Citizenship: India		

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Original Patent

Patentee:

Loi Nguyen

Ravishankar Sundaresan

Patent No.: 5,710,461

Title:

SRAM CELL FABRICATION

WITH INTERLEVEL

DIELECTRIC PLANARIZATION

Issued:

January 20, 1998

Atty Dk No.: 93-C-078C1

Reissue Application

Applicant:

Loi Nguyen

Ravishankar Sundaresan

Serial No.:

Title: SRAM CELL FABRICATION

WITH INTERLEVEL

DIELECTRIC PLANARIZATION

Filing Date: January 20, 2000

Atty Dk No.: 93-C-078C1-RE (1678-20)

CERTIFICATE OF MAILING OR TRANSMISSION

"Express Mail" mailing label number: EK434158406US

Date of Deposit: January 20, 2000

I hereby certify that this paper or fee is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR, Section 1.10 on the date indicated above and is addressed to the Assistant Commissioner for Patents, Box Patent Application, Washington, D.C. 20231 by

ASSENT OF ASSIGNEE

TO THE ASSISTANT COMMISSIONER FOR PATENTS:

STMicroelectronics, Inc., assigne	ee of U.S. Patent No. 5,710,461, consents to
the filing of reissue application No	(or the present application, if
filed with the initial application papers) for t	he reissue of U.S. Patent No. 5,710,461.
	STMicroelectronics, Inc.
	Archie McK. Malone
	Executive Vice President
	Finance & C.F.O. and Treasurer

PTO/SB/54 (12-97)
Approved for use through 9/30/00. OMB 0651-0033
Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number.

REISSUE APPLICATION BY THE ASSIGNEE, OFFER TO SURRENDER PATENT

Docket Number (Optional)

93-C-078C1

Name of Patentee(s):	e patent based on the original patent identified below.
, ,	
Loi Nguyen and Ravishanka Patent Number	ar Sundaresan Date Patent Issued
5,710,461	January 20, 1998
Title of Invention	
SRAM CELL FABRICATION WIT	TH INTERLEVEL DIELECTRIC PLANARIZATION
STMicroelectronics, INc.	is the assignee of the entire interest in the original patent.
I offer to surrender the original patent.	
A certificate under 37 CFR 3.73(b)	is attached.
l am authorized to act on behalf of the a	assignee.
were made with the knowledge that willful fine or imprisonment, or both, under 18 U.	herein of my own knowledge are true and that all of are believed to be true; and further that these statements false statements and the like so made are punishable by S.C. 1001 and that such willful false statements may ny patent issued thereon, or any patent to which this
Name of assignee	
STMicroelectronics, Inc.	
Signature of person signing for assignee	Date
Typed or printed name and title of person s	igning for assignee
	tive Vice President, Finance & C.F.O.

Burden Hour Statement: This form is estimated to take 0.1 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.

CERTIFICATE UNDER 37 C.F.R. § 3.73(b)

Applica	nt:		Loi Nguyen and Ravishankar Sundaresan
Reissue	Applica	tion No.:	Filed:
For:			SRAM CELL FABRICATION WITH INTERLEVEL DIELECTRIC PLANARIZATION
STMicr		nics, Inc., f Assignee)	a corporaton (Type of Assignee, e.g., corporation, partnership, government agency, etc.)
certifies either:	s that it is	s the assig	nee of the entire right, title and interest in the patent application identified above by virtue of
A.	[X]		gnment from inventors of the patent application identified above. The assignment was in the Patent and Trademark Office at Reel 6828 Frame 0050 (copy enclosed).
B.	[]		of title from the inventor(s), of the patent application identified above, to the current s as shown below:
	1.	The doc	To:To: ument was recorded in the Patent and Trademark Office at Reel or for which a copy thereof is attached.
	2.	The doc	To:ument was recorded in the Patent and Trademark Office at Reel or for which a copy thereof is attached.
	3.	The doc	To: ument was recorded in the Patent and Trademark Office at Reel or for which a copy thereof is attached.
	[]	Addition	nal documents in the chain of title are listed on a supplemental sheet.
	[]	Copies o	of assignments or other documents in the chain of title are attached.
and, to		_	has reviewed all the documents in the chain of title of the patent application identified above gned's knowledge and belief, title is in the assignee identified above.
	The un	dersigned	(whose title is supplied below) is empowered to act on behalf of the assignee.
willful Title 18	rmation a false star S of the U	and belief tements, a	that all statements made herein of my own knowledge are true, and that all statements made are believed to be true; and further, that these statements are made with the knowledge that and the like so made, are punishable by fine or imprisonment, or both, under Section 1001, tes Code, and that such willful false statements may jeopardize the validity of the application con.
Date:			
Name:		Archie M	McK. Malone
Title:		Executive Vice President, Finance & C.F.O. and Treasurer	
Signatu	re:	·	